

# 1MBI1200U4C-170

# IGBT MODULE (U series) 1700V / 1200A / 1 in one package

# Features

High speed switching Voltage drive Low Inductance module structure

# Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

## Maximum Ratings and Characteristics

## Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage	Vces			1700	V	
Gate-Emitter voltage	Vges			±20	V	
Collector current	lc	Continuous	Tc=25°C	1600		
			Tc=80°C	1200		
	Ic pulse	1ms	Tc=25°C	3200	۸	
			Tc=80°C	2400	A	
	-lc			1200		
	-lc pulse	1ms		2400		
Collector power dissipation	Pc	1 device		7350	W	
Junction temperature	Тј			150	°C	
Storage temperature	Tstg			-40 to +125	°C	
Isolation voltage Between terminal and copper base (*1)	Viso	AC : 1min.		3400	VAC	
	Mounting (*2)			5.75		
Screw torque	Main Terminals (*2)			10	N∙m	
	Sense Terminals (*2)			2.5		

Note \*1: All terminals should be connected together when isolation test will be done.

Note \*2: Recommendable value : Mounting : 4.25-5.75 N·m (M6), Main Terminal : 8-10 N·m (M8), Sense Terminal : 1.7-2.5 N·m (M4)

#### • Electrical characteristics (at Tj= 25°C unless otherwise specified)

ltomo	Symbolo	Symbols Conditions		Characteristics			Unite
Items	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	ICES	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1700V		-	-	1.0	mA
Gate-Emitter leakage current	Iges	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	2400	nA
Gate-Emitter threshold voltage	V <sub>GE (th)</sub>	V <sub>CE</sub> = 20V, I <sub>c</sub> = 1200mA		5.5	6.5	7.5	V
Collector-Emitter saturation voltage	V <sub>CE (sat)</sub>	) V <sub>GE</sub> = 15V I <sub>C</sub> = 1200A	Tj=25°C	-	2.43	2.61	V
	(main terminal)		Tj=125°C	-	2.83	-	
	V <sub>CE (sat)</sub>		Tj=25°C	-	2.25	2.40	
	(chip)		Tj=125°C	-	2.65	-	
Input capacitance	Cies	$V_{GE} = 0V, V_{CE} = 10V, f = 10V$	1MHz	-	112	-	nF
Turn-on time	ton			-	1.80	-	μs
	tr	$V_{cc} = 900V, I_c = 1200A$	-	0.85	-		
	toff	V <sub>GE</sub> = ±15V, Tj = 125°C R <sub>gon</sub> = 3.9Ω, R <sub>goff</sub> = 1.5Ω		-	1.30	-	
	tf	1.012 - 1.012, 1.012	-	0.35	-		
Forward on voltage	VF	) V <sub>GE</sub> = 0V I <sub>F</sub> = 1200A	Tj=25°C	-	1.98	2.36	v
	(main terminal)		Tj=125°C	-	2.18	-	
	VF		Tj=25°C	-	1.80	2.15	
	(chip)		Tj=125°C	-	2.00	-	
Reverse recovery time	trr	IF = 1200A		-	0.35	-	μs
Lead resistance, terminal-chip (*3)	R lead			-	0.146	-	mΩ

Note \*3: Biggest internal terminal resistance among arm.

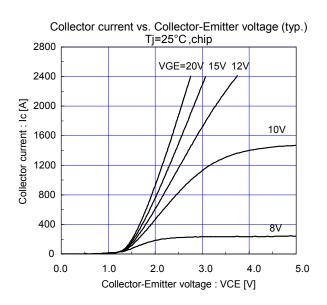
# Thermal resistance characteristics

Symbolo	Conditions	Characteristics			Units	
Symbols	Conditions	min.	typ.	max.	Units	
Dth(i, a)	IGBT	-	-	0.017		
Thermal resistance (1device)         Rth(j-c)	FWD	-	-	0.030	°C/W	
Rth(c-f)	with Thermal Compound (*4)	-	0.006	-	]	
	Symbols       Rth(j-c)       Rth(c-f)	Rth(j-c) IGBT FWD	SymbolsConditionsRth(j-c)IGBT-FWD-	SymbolsConditionsmin.typ.Rth(j-c)IGBTFWD	Symbols         Conditions         min.         typ.         max.           Rth(j-c)         IGBT         -         -         0.017           FWD         -         -         0.030	

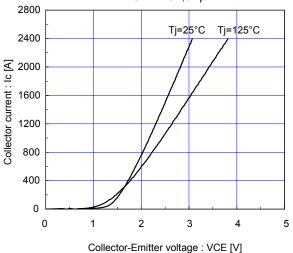
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

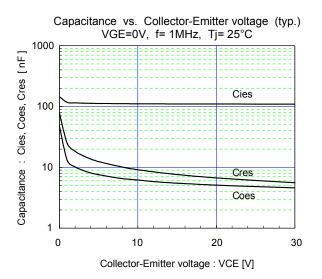


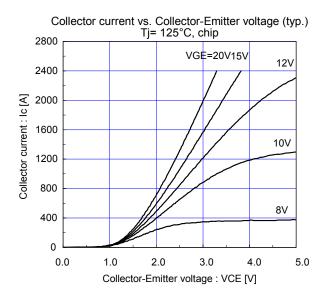
# Characteristics (Representative)



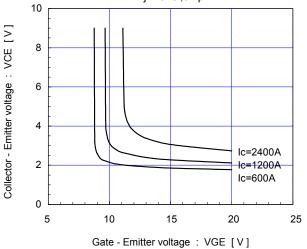
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) VGE=+15V,chip

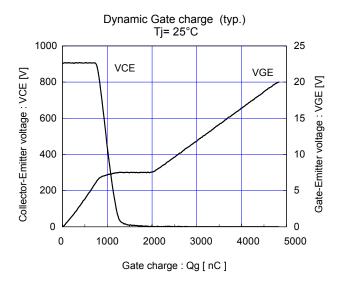


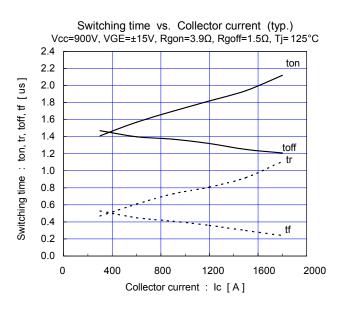


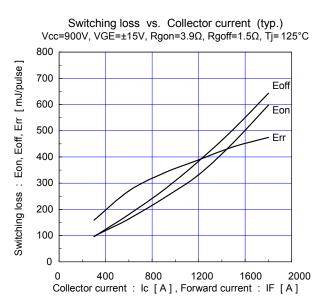


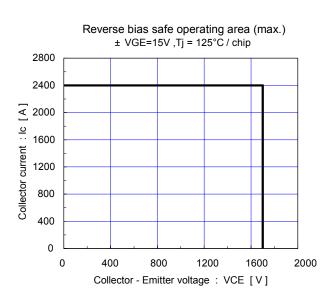
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj=25°C ,chip

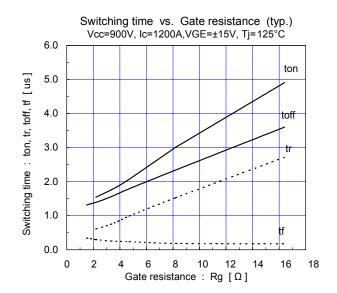


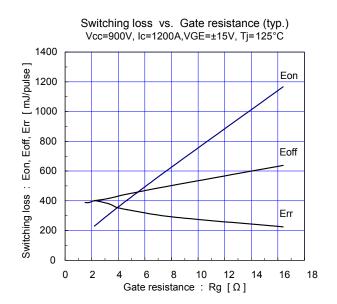


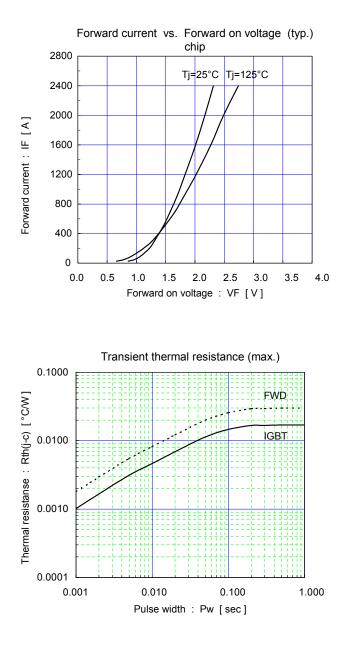


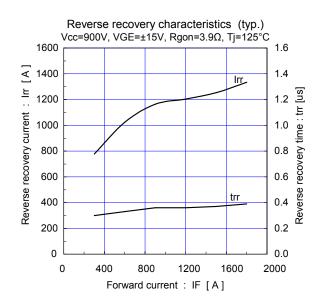


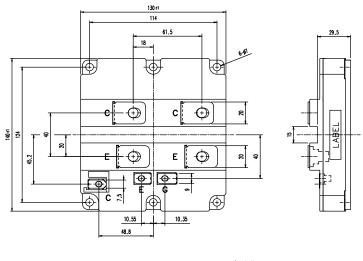


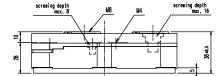




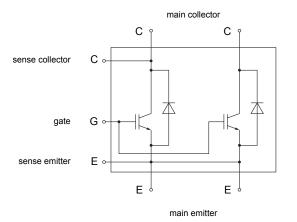








# Equivalent Circuit Schematic



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